DATA SHEET



SILICON TRANSISTOR ARRAY $\mu PA1458$

NPN SILICON POWER TRANSISTOR ARRAY LOW SPEED SWITCHING USE (DARLINGTON TRANSISTOR) INDUSTRIAL USE

DESCRIPTION

The μ PA1458 is NPN silicon epitaxial Darlington Power Transistor Array that built in Surge Absorber and 4 circuits designed for driving solenoid, relay, lamp and so on.

FEATURES

- Surge Absorber (C B) built in.
- Easy mount by 0.1 inch of terminal interval.
- High hre for Darlington Transistor.

ORDERING INFORMATION

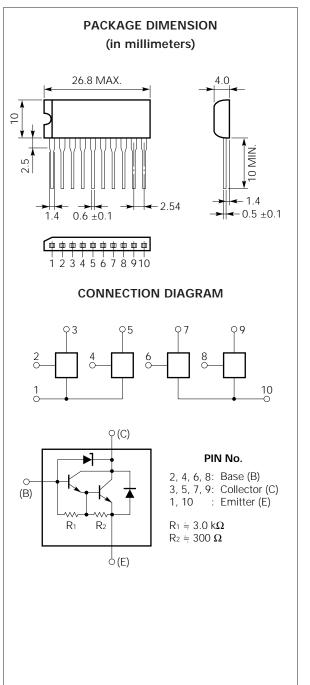
Part Number	Package	Quality Grade	
μPA1458H	10 Pin SIP	Standard	

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Collector to Base Voltage	Исво	60 ±10	V
Collector to Emitter Voltage	Vceo	60 ±10	V
Emitter to Base Voltage	Vebo	7	V
Surge Sustaining Energy	Eceo(sus)	25	mJ/unit
Collector Current (DC)	C(DC)	±5	A/unit
Collector Current (pulse)	IC(pulse)*	±10	A/unit
Collector Current	CBS(DC)	5	mA/unit
Base Current (DC)	B(DC)	0.5	A/unit
Total Power Dissipation	Pt1**	3.5	W
Total Power Dissipation	Рт2***	28	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg -5	5 to +1	50 °C

- * PW \leq 300 μs , Duty Cycle \leq 10 %
- ** 4 Circuits, Ta = 25 °C
- *** 4 Circuits, Tc = 25 °C



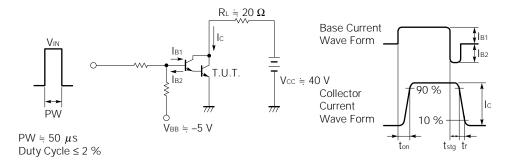
The information in this document is subject to change without notice.

ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

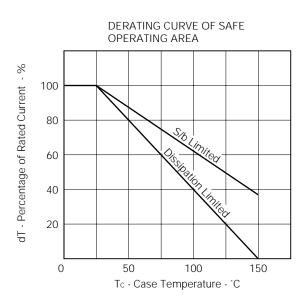
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Collector Leakage Current	Ices			10	μA	$V_{CE} = 40 V$	
Emitter Leakage Current	Ево			10	mA	$V_{EB} = 5 V$, Ic = 0	
Collector to Emitter Sustaining Voltage	VCEO(sus)	50	60	70	V	Ic = 3 A, L = 1 mH	
DC Current Gain	hfei *	2000	7000	20000	_	Vce = 2 V, Ic = 2 A	
DC Current Gain	hfe2 *	500	3000		—	$V_{CE} = 2 V$, $I_C = 4 A$	
Collector Saturation Voltage	VCE(sat) *		0.9	1.5	V	Ic = 2 A, I _B = 2 mA	
Base Saturation Voltage	VBE(sat) *		1.6	2	V	Ic = 2 A, IB = 2 mA	
Turn On Time	ton		1		μs	Ic = 2 A	
Storage Time	tstg		7		μs	I _{B1} = −I _{B2} = 2 mA V _{CC} ≒ 40 V, R _L ≒ 20 Ω See test circuit	
Fall Time	tr		2		μs		

* PW \leq 350 μ s, Duty Cycle \leq 2 % / pulsed

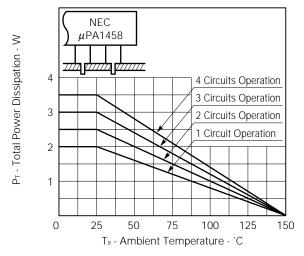
SWITCHING TIME TEST CIRCUIT

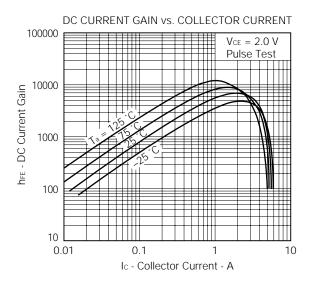


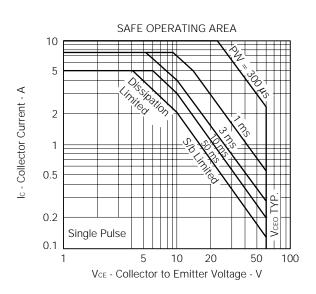




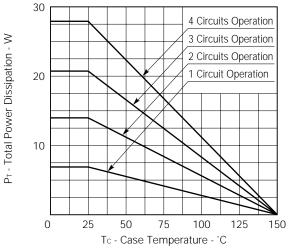




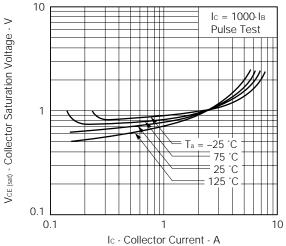


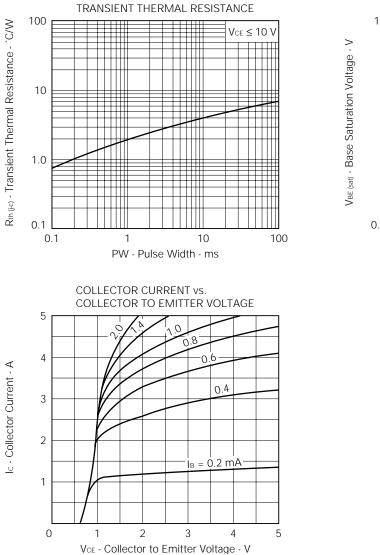


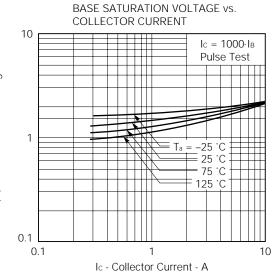
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT







REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134

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Application examples recommended by NEC Corporation

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.

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